

LIGHT EMITTING DIODE SPECIFICATION

Revise History

Rev.	Descriptions	Date	Page
1.0	-	23-10-2017	-
2.0	Renew form	15-12-2018	-
2.1	Renew form	10-11-2020	-
2.2	Renew form	27-12-2023	-

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Features:

- Long operating life
- Low Power Consumption
- Low voltage DC operated
- RoHS Compliant
- Anti-ultraviolet Packaging

**Application:**

- Optoelectronic switch.
- IR Touch-Panel.
- Industrial IR equipment.
- Consumer Electronics.
- High Speed IR Communications.

Part Number	Dice Material	Emitted Color	Lens Color
IE-3528IR-SB-L-CE2	GaAlAs	Infrared	Water Clear

Electro-Optical Characteristics(Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Radiant Intensity ^{*1}	Ee	60.0	-	120.0	mw/sr	IF=60mA
Radiation Bandwidth	$\Delta\lambda$	-	50	-	nm	
Forward Voltage	VF	1.10	-	1.60	V	
Peak Wavelength ^{*3}	λ_p	-	850	-	nm	
Viewing Angle ^{*2}	2 $\theta_{1/2}$	-	30	-	deg	
Reverse Current	IR	-	-	10	uA	VR=5V

Notes :

1. Radiant Intensity is measured with a light sensor and filter combination that approximates the CIE eye-response curve.
2. $\theta_{1/2}$ is the off-axis angle at which the luminous intensity is half the axial luminous intensity.
3. The peak wavelength(λ_p) is derived from the CIE chromaticity diagram and represents the single wavelength which defines the color of the device.

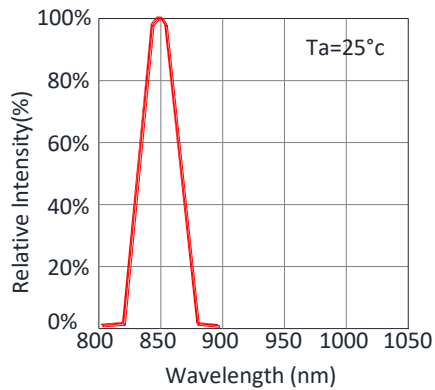
Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Max.	Unit
Power Dissipation	Pd	160	mW
Peak Forward Current ^{*1}	IFP	1000	mA
Forward Current ^{*2}	IF	100	mA
Reverse Voltage	VR	5	v
Operating Temperature Range	Topr	-40to+85	°C
Storage Temperature Range	Tstg	-40to+85	°C
Reflow Soldering	Tsld	260°C for 5secs	

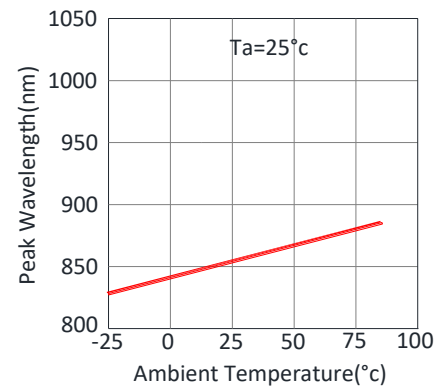
Notes: 1. Derate linearly as shown in derating curve. 2. Duty Factor = 10%, Frequency = 1 kHz

Optical & Electrical Characteristics

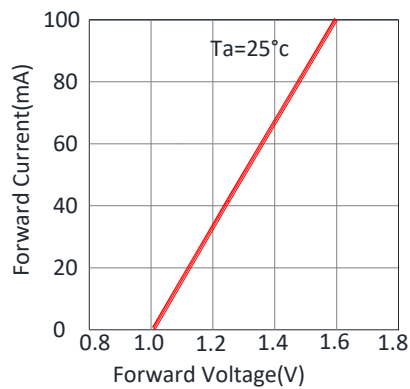
Relative Intensity vs.Wavelength



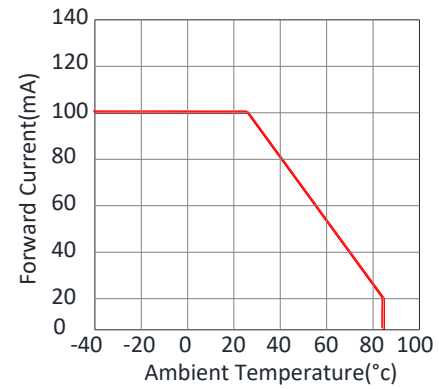
Peak Wavelength vs.Ambient Temperature(°C)



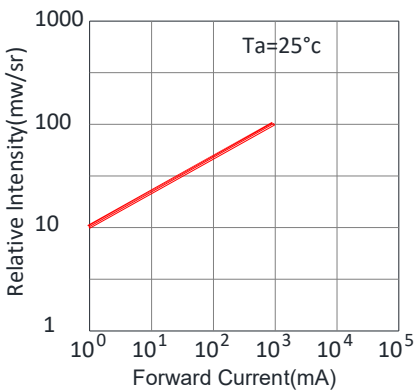
Forward Current vs.Forward Voltage



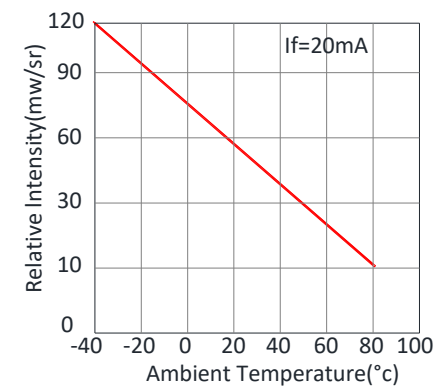
Forward Current vs.Ambient Temperature



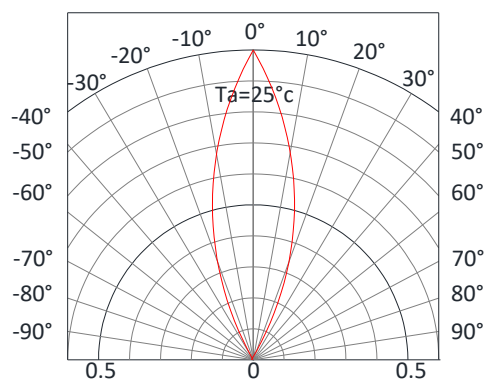
Relative Intensity vs.Forward Current



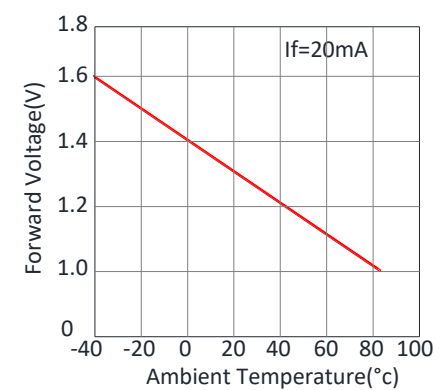
Relative Intensity vs.Ambient Temperature



Radiation Pattern



Forward Voltage vs.Ambient Temperature



Bin Limits**Radiant Intensity(Unit:mW/sr)**

Bin Code	Min	Max	Condition
1	60.0	80.0	IF=60mA
2	80.0	100.0	
3	100.0	120.0	
4	-	-	
5	-	-	

Bin Range Of Forward Voltage (Unit:V)

Bin Code	Min	Max	Condition
V1	1.1	1.2	IF=60mA
V2	1.2	1.3	
V3	1.3	1.4	
V4	1.4	1.5	
V5	1.5	1.6	

Notes:

- 1.Radiant Intensity measurement tolerance: $\pm 10\%$.
- 2.Forward voltage measurement tolerance: $\pm 0.1V$.

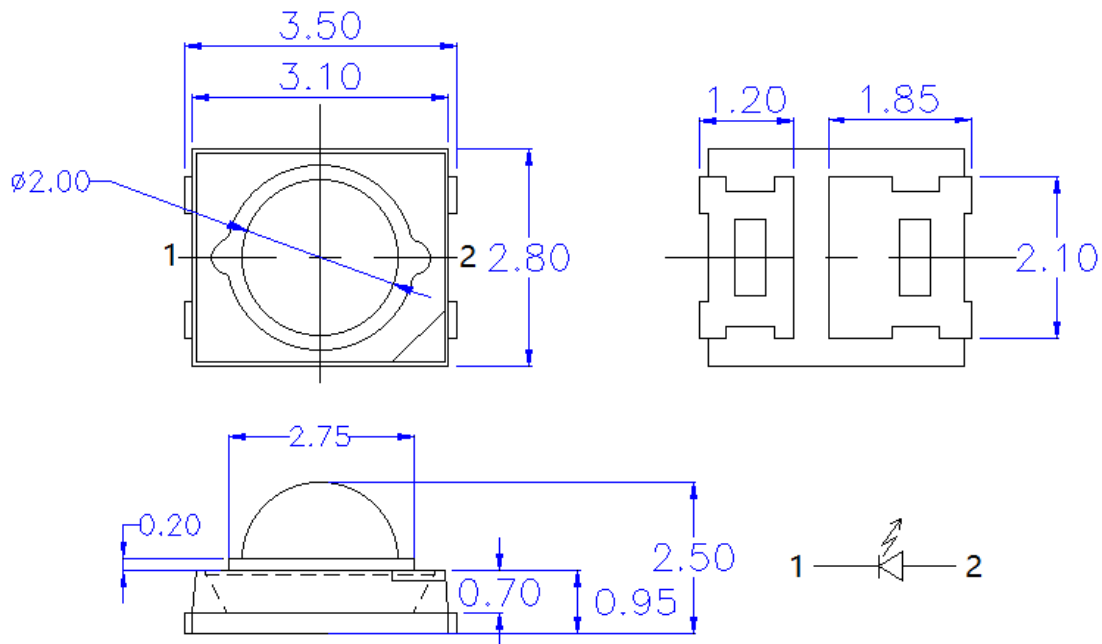
Reliability Test Items And Conditions

Test Items	Reference	Test Conditions	Time	Quantity	Criterion
Thermal Shock	MIL-STD-202G	-40°C (30min) -100°C (30min)	100 Cycles	22	0/22
Temperature And Humidity Cyclic	JEITA ED-4701 200 203	-10°C~65°C ; 0%~90%RH	10cycles	22	0/22
High Temperature Storage	JEITA ED -4071 200 201	Ta=100°C	1000H	22	0/22
Low Temperature Storage	JEITA ED -4071 200 202	Ta=-40°C	1000H	22	0/22
High Temperature High Humidity Storage	JEITA ED -4071 100 103	Ta=85°C ; RH=85%	1000H	22	0/22
High Temperature Life Test	JESD22-A108D	Ta=80°C	1000H	22	0/22
Life Test	JESD22-A108D	Ta=25°C IF=20mA	1000H	22	0/22
Resistance to Soldering Heat	GB/T 4937,II , 2.2&2.3	Tsol*=(240±5) °C10secs	2 times	22	0/22

Criteria For Judging Damage

Test Items	Symbol	Test Conditions	Criteria For Judging Damage
Forward Voltage	V _F	I _F =I _{FT}	Initial Data±10%
Reverse Current	I _R	V _R =5V	I _R ≤10uA
Luminous Intensity	I _V	I _F =I _{FT}	Average I _V degradation≤30% ; Single LED I _V degradation≤50%
Resistance to Soldering Heat	-	-	Material without internal cracks,no material between stripped,no dead light

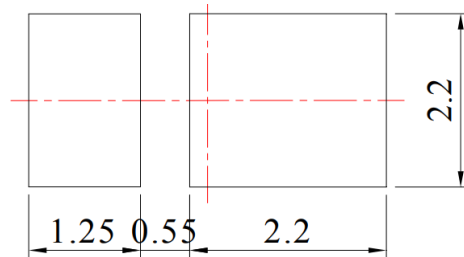
Product size (Unit:mm)



NOTES :

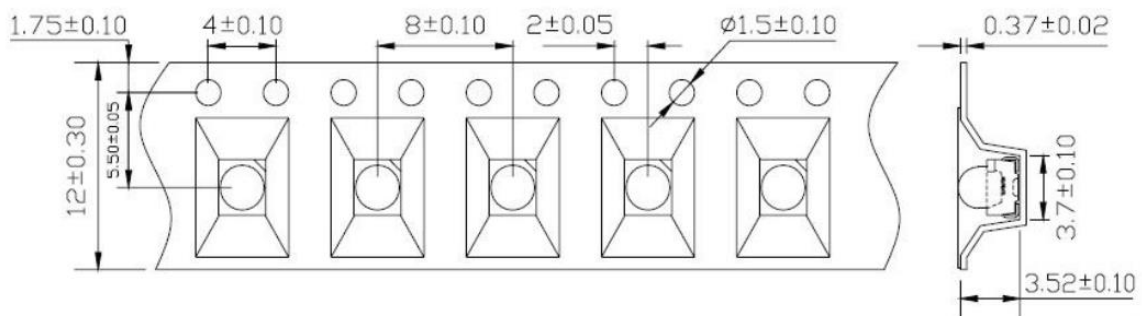
1. All dimensions are in millimeters (inches)
2. Tolerances are $\pm 0.2\text{mm}$ (0.008inch) unless otherwise noted

Recommended Soldering Pad Design (Unit:mm)

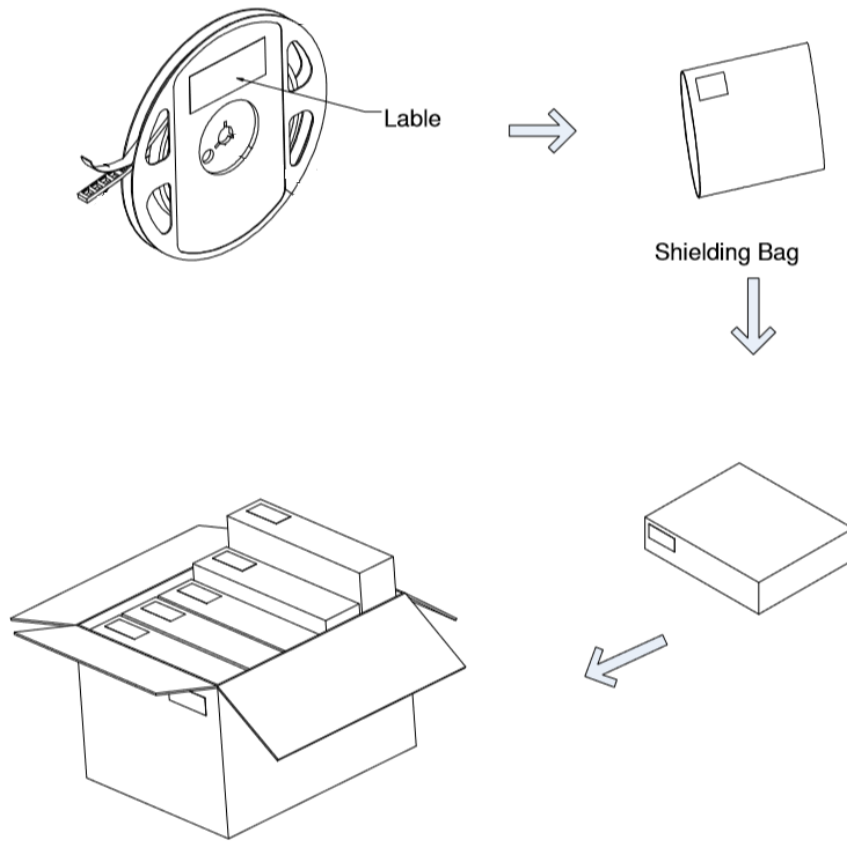


Taping and package Spec

- Tape Specification: 2,000pcs Per Reel



Packaging



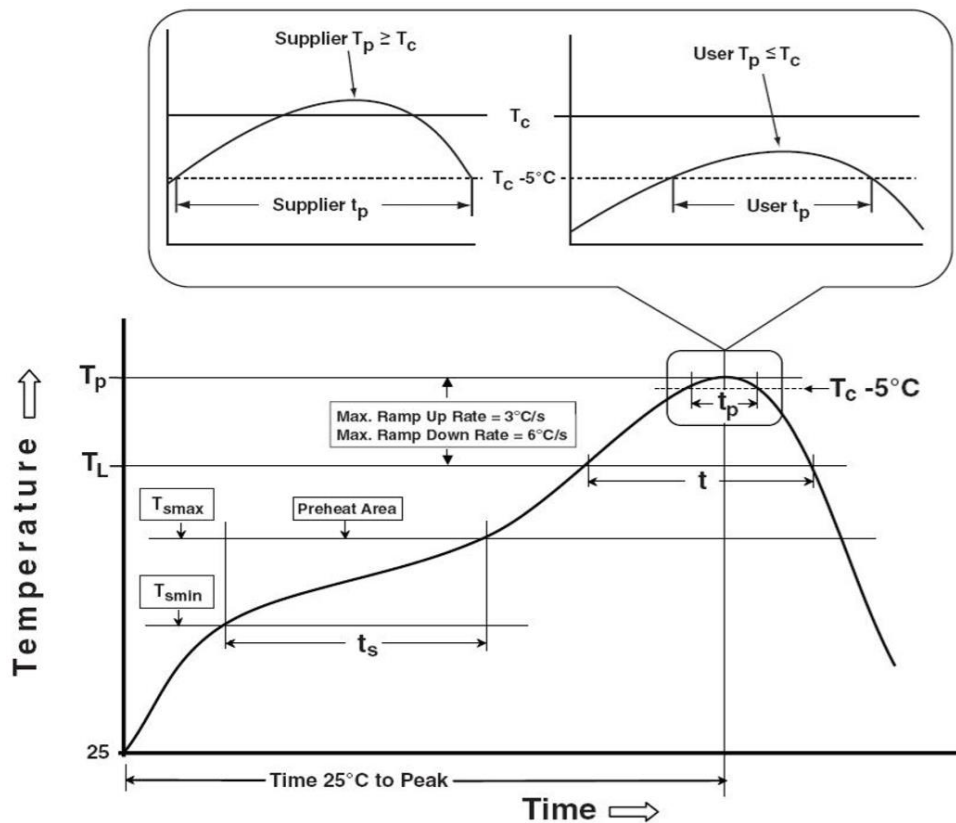
LabelStyle

MANUFACTURER	
	
P/N:XXXXXXXXXXXXXXXXXX	
Emitting Color: XXXX	
HUE: XXX-XXX nm	
IV : XXX-XXX mcd	
VF: XX-XX V	
QTY: XX PCS	
BIN Code: XX	
DATE: XXXX/XX/XX	
	
LOT NO.:XXXXXXX	

Table of Classification Reflow Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat & Soak	100 °C	150 °C
Temperature min (T _{smin})	150°C	200 °C
Temperature max (T _{smax})	60-120 seconds	60-120 seconds
Time (T _{smin} to T _{smax}) (t _s)		
Average ramp-up rate (T _{smax} to T _p)	3 °C/second max	3 °C/second max
Liquidous temperature (T _L)	183 °C	217 °C
Time at liquidous (t _L)	60-150 seconds	60-150 seconds
Peak package body temperature (T _p)*	230 °C ~235 °C	255 °C ~260 °C
Classification temperature (T _c)	235 °C	260 °C
Time (t _p) within 5 °C of the specified Classification temperature (T _c)	20 seconds	30 seconds
Average ramp-down rate (T _p to T _{smax})	6 °C/second max	6 °C/second max
Time 25 °C to peak temperature	6 minutes max	8 minutes max

1. Tolerance for peak profile temperature (T_p) is defined as a supplier minimum and a user maximum.
2. Tolerance for time at peak profile temperature (t_p) is defined as a supplier minimum and a user maximum.



Precautions

1. Storage :

- Moisture proof and anti-electrostatic package with moisture absorbent material is used, to keep moisture to a minimum.
- Before opening the package, the product should be kept at 30°C or less and humidity less than 60% RH, and be used within a year.
- After opening the package, the product should be stored at 30°C or less and humidity less than 10%RH. It is recommended that the product be operated at the workshop condition of 30°C or less and humidity less than 60%RH.
- If the moisture absorbent material has faded away or the LEDs have exceeded the storage time, baking treatment should be performed based on the following condition: (70±5)°C for 24 hours.

2. Static Electricity :

- Static electricity or surge voltage damages the LEDs. Damaged LEDs will show some unusual characteristic such as the forward voltage becomes lower, or the LEDs do not light at the low current. All devices, equipment and machinery must be properly grounded. At the same time, it is recommended that wrist bands or anti-electrostatic gloves, anti-electrostatic containers be used when dealing with the LEDs.

3. Vulcanization :

- LED curing is due to sulfur being in bracket and the +1 price of silver in the chemical reaction generated Ag₂S in the process. It will lead to the capacity of reflecting of silver layer reducing, light color temperature drift and serious decline, seriously affecting the performance of the product. So we should take corresponding measures to avoid vulcanization, such as to avoid using sulphur volatile substances and keeping away from high sulphur content of the material.

4. Handling Precautions:

- Handle the component along the side surfaces by using forceps or appropriate tools.
- Do not directly touch or handle the silicone lens surface. It may damage the internal circuitry.
- Do not stack together assembled PCBs containing exposed LEDs. Impact may scratch the epoxy resin lens or damage the internal circuitry.
- Compare to epoxy encapsulant that is hard and brittle, silicone is softer and flexible. Although its characteristic significantly reduces thermal stress, it is more susceptible to damage by external mechanical force. As a result, special handling precautions need to be observed during assembly using silicone encapsulated LED products. Failure to comply might lead to damage and premature failure of the LED.

